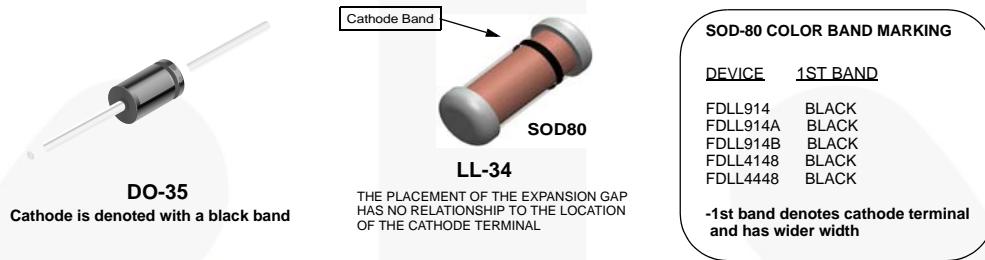




June 2015

1N/FDLL 914/A/B / 916/A/B / 4148 / 4448 — Small Signal Diode

1N/FDLL 914/A/B / 916/A/B / 4148 / 4448 Small Signal Diode



Ordering Information

Part Number	Marking	Package	Packing Method
1N914	914	DO-204AH (DO-35)	Bulk
1N914_T50A	914	DO-204AH (DO-35)	Ammo
1N914TR	914	DO-204AH (DO-35)	Tape and Reel
1N914ATR	914A	DO-204AH (DO-35)	Tape and Reel
1N914B	914B	DO-204AH (DO-35)	Bulk
1N914BTR	914B	DO-204AH (DO-35)	Tape and Reel
1N916	916	DO-204AH (DO-35)	Bulk
1N916A	916A	DO-204AH (DO-35)	Bulk
1N916B	916B	DO-204AH (DO-35)	Bulk
1N4148	4148	DO-204AH (DO-35)	Bulk
1N4148TA	4148	DO-204AH (DO-35)	Ammo
1N4148_T26A	4148	DO-204AH (DO-35)	Ammo
1N4148_T50A	4148	DO-204AH (DO-35)	Ammo
1N4148TR	4148	DO-204AH (DO-35)	Tape and Reel
1N4148_T50R	4148	DO-204AH (DO-35)	Tape and Reel
1N4448	4448	DO-204AH (DO-35)	Bulk
1N4448TR	4448	DO-204AH (DO-35)	Tape and Reel
FDLL914	Black	SOD-80	Tape and Reel
FDLL914A	Black	SOD-80	Tape and Reel
FDLL914B	Black	SOD-80	Tape and Reel
FDLL4148	Black	SOD-80	Tape and Reel
FDLL4148_D87Z	Black	SOD-80	Tape and Reel
FDLL4448	Black	SOD-80	Tape and Reel
FDLL4448_D87Z	Black	SOD-80	Tape and Reel

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit	
V_{RRM}	Maximum Repetitive Reverse Voltage	100	V	
I_O	Average Rectified Forward Current	200	mA	
I_F	DC Forward Current	300	mA	
I_f	Recurrent Peak Forward Current	400	mA	
I_{FSM}	Non-repetitive Peak Forward Surge Current	Pulse Width = 1.0 s	1.0	A
		Pulse Width = 1.0 μs	4.0	A
T_{STG}	Storage Temperature Range	-65 to +200	$^\circ\text{C}$	
T_J	Operating Junction Temperature Range	-55 to +175	$^\circ\text{C}$	

Note:

1. These ratings are limiting values above which the serviceability of the diode may be impaired.

Thermal Characteristics

Symbol	Parameter	Max.	Unit
		1N/FDLL 914/A/B / 916/A/B / 4148 / 4448	
P_D	Power Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	300	$^\circ\text{C}/\text{W}$

Electrical Characteristics⁽²⁾

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V_R	Breakdown Voltage	$I_R = 100 \mu\text{A}$	100		V
		$I_R = 5.0 \mu\text{A}$	75		V
V_F	Forward Voltage	$I_F = 5.0 \text{ mA}$	0.62	0.72	V
		$I_F = 5.0 \text{ mA}$	0.63	0.73	V
		$I_F = 10 \text{ mA}$		1.0	V
		$I_F = 20 \text{ mA}$		1.0	V
		$I_F = 20 \text{ mA}$		1.0	V
		$I_F = 100 \text{ mA}$		1.0	V
I_R	Reverse Leakage	$V_R = 20 \text{ V}$		0.025	μA
		$V_R = 20 \text{ V}, T_A = 150^\circ\text{C}$		50	μA
		$V_R = 75 \text{ V}$		5.0	μA
C_T	Total Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		2.0	pF
		$V_R = 0, f = 1.0 \text{ MHz}$		4.0	pF
t_{rr}	Reverse Recovery Time	$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V (600 mA)}$ $I_{rr} = 1.0 \text{ mA}, R_L = 100 \Omega$		4.0	ns

Note:

2. Non-recurrent square wave $P_W = 8.3 \text{ ms}$.

Typical Performance Characteristics

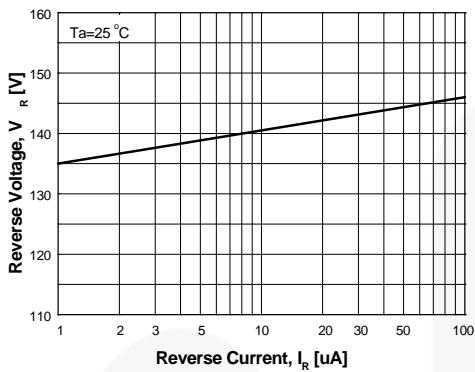


Figure 1. Reverse Voltage vs. Reverse Current
 V_F - 1.0 to 100 μA

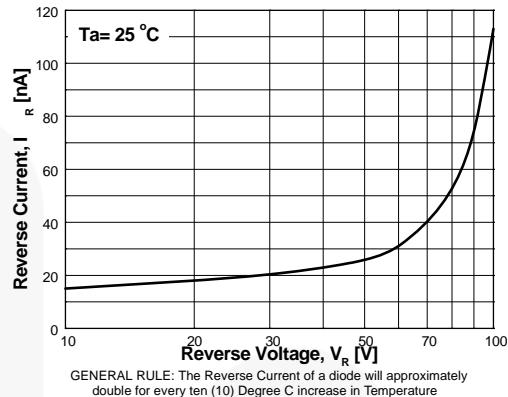


Figure 2. Reverse Current vs. Reverse Voltage
 I_R - 10 to 100 V

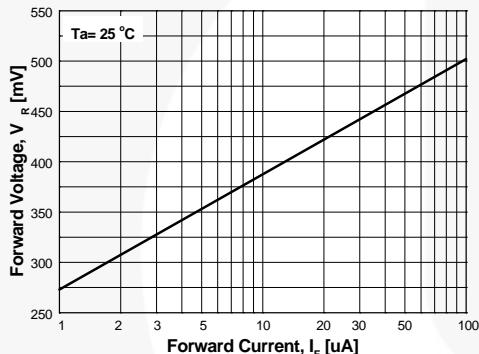


Figure 3. Forward Voltage vs. Forward Current
 V_F - 1 to 100 μA

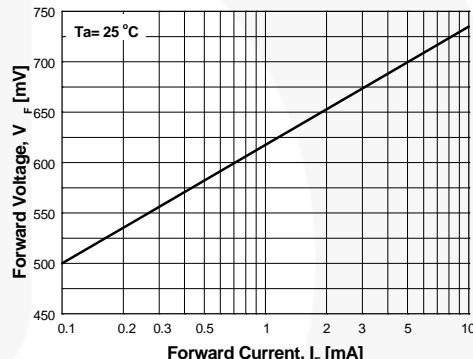


Figure 4. Forward Voltage vs. Forward Current
 V_F - 0.1 to 10 mA

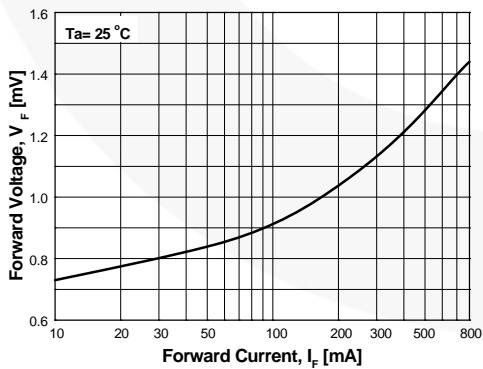


Figure 5. Forward Voltage vs. Forward Current
 V_F - 10 to 800 mA

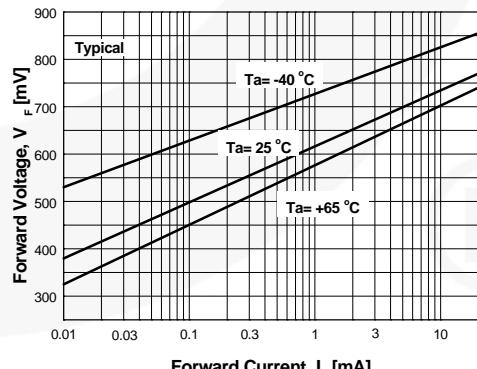


Figure 6. Forward Voltage vs. Ambient Temperature
 V_F - 0.01 - 20 mA (- 40 to +65°C)

Typical Performance Characteristics (Continued)

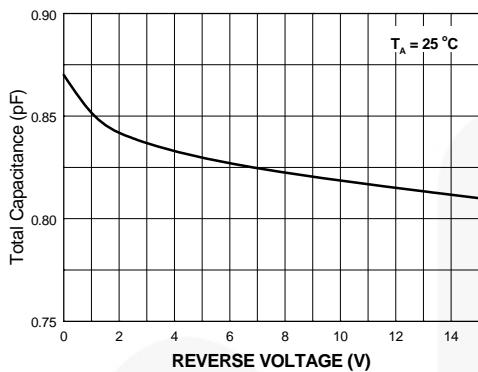


Figure 7. Total Capacitance

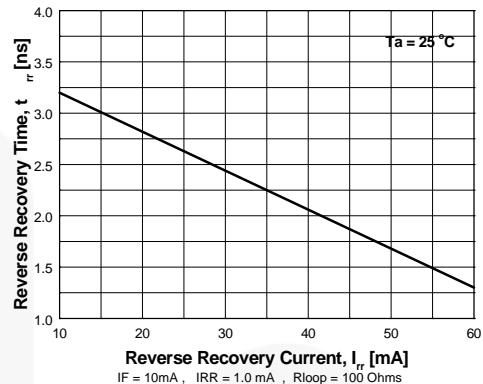


Figure 8. Reverse Recovery Time vs. Reverse Recovery Current

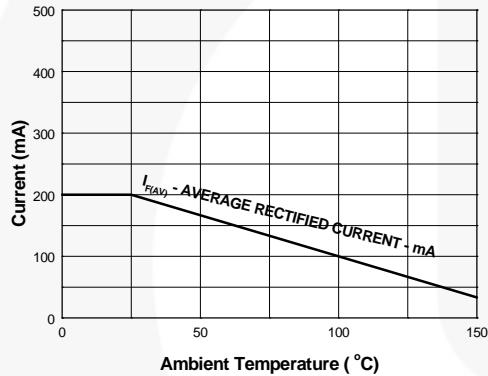


Figure 9. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (T_A)

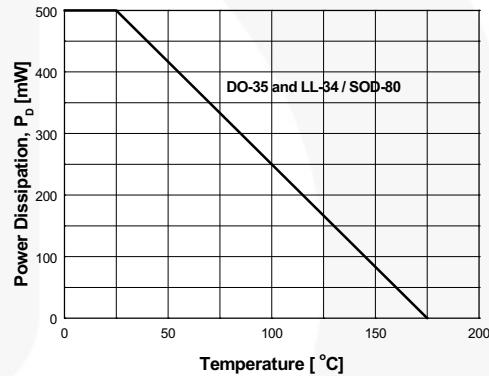


Figure 10. Power Derating Curve

Physical Dimensions

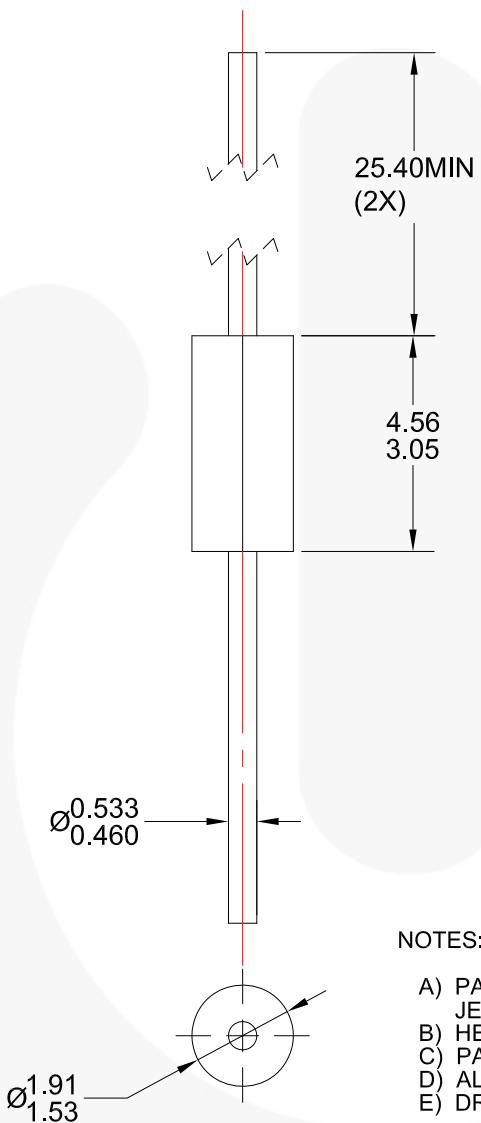
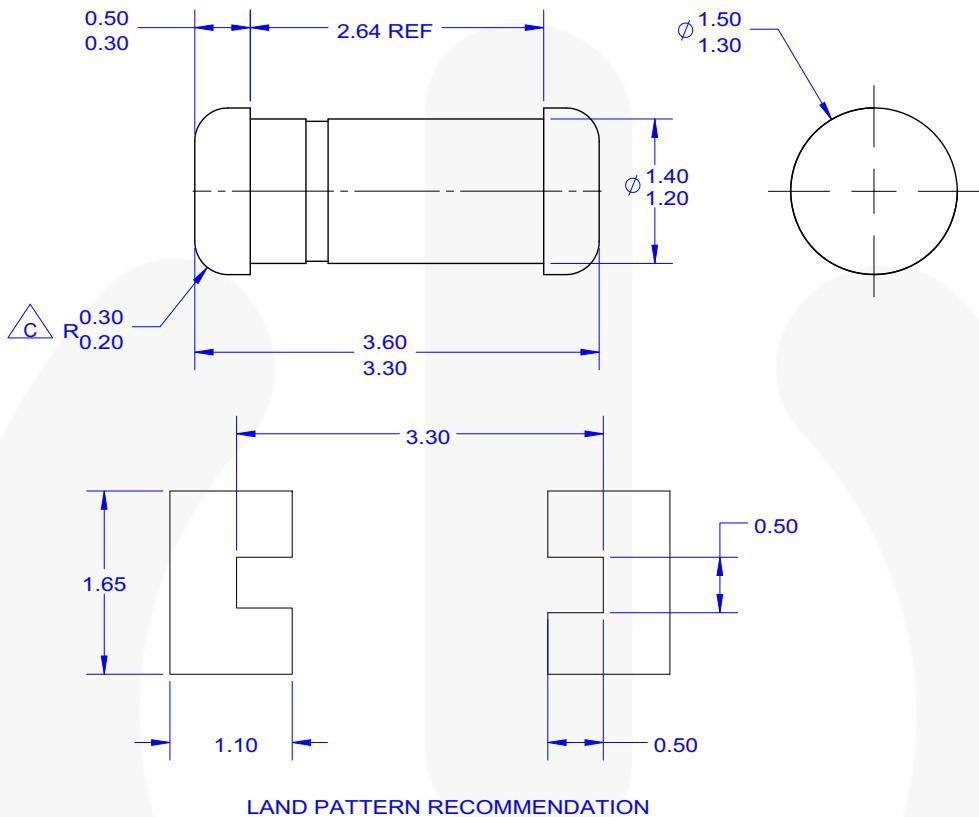


Figure 11. AXIAL LEADED, GLASS, JEDEC DO204, VARIATION AH, DO-204AH (DO-35)

Physical Dimensions (Continued)



NOTES: UNLESS OTHERWISE SPECIFIED

- A) PACKAGE STANDARD REFERENCE:
JEDEC DO-213, VARIATION AC.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) CORNER RADIUS IS OPTIONAL.
- D) LAND PATTERN RECOMMENDATION PER IPC DIOMELF3414N
- E) DRAWING FILE NAME: SOD80A REV3



Figure 12. 2-Terminal, SOD-80, JEDEC DO-213AC, MINI-MELF



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